

# KSB1116/1116A

# **Audio Frequency Power Amplifier & Medium Speed Switching**

Complement to KSD1616/1616A



# **PNP Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Paramet	er	Ratings	Units
V <sub>CBO</sub>	Collector-Base Voltage	: KSB1116	-60	V
		: KSB1116A	-80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	: KSB1116	-50	V
		: KSB1116A	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage		-6	V
I <sub>C</sub>	Collector Current (DC)		-1	Α
I <sub>CP</sub>	* Collector Current (Pulse)		-2	Α
P <sub>C</sub>	Collector Power Dissipation		0.75	W
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		-55 ~ 150	°C

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

### **Electrical Characteristics** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -60V, I_{E} = 0$			-100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -6V, I_{C} = 0$			-100	nA
h <sub>FE1</sub>	* DC Current Gain : KSB1116	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA	135		600	
	: KSB1116A		135		400	
$h_{FE2}$		$V_{CE} = -2V, I_{C} = -1A$	81			
V <sub>BE</sub> (on)	* Base-Emitter On Voltage	$V_{CE}$ = -2V, $I_{C}$ = -50mA	-600	-650	-700	mV
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA		-0.2	-0.3	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA		-0.9	-1.2	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = -10V, I <sub>E</sub> =0, f=1MHz		25		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA	70	120		MHz
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = -10V, I <sub>C</sub> = -100mA		0.07		μs
t <sub>STG</sub>	Storage Time	I <sub>B1</sub> = -I <sub>B2</sub> = -10mA		0.7		μs
t <sub>F</sub>	Fall Time	V <sub>BE</sub> (off)= 2~3V		0.07		μs

<sup>\*</sup> Pulse Test: PW ≤350μs, Duty Cycle≤2%

## **h**<sub>FE</sub> Classification

Classification	Y	G	L
h <sub>FE1</sub>	135 ~ 270	200 ~ 400	300 ~ 600

# **Typical Characteristics**

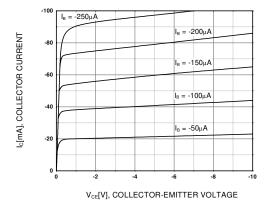


Figure 1. Static Characteristic

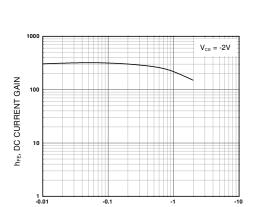


Figure 3. DC current Gain

I<sub>C</sub>[mA], COLLECTOR CURRENT

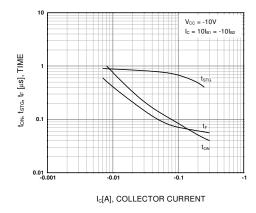


Figure 5. Switching Time

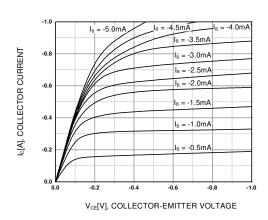


Figure 2. Static Characteristic

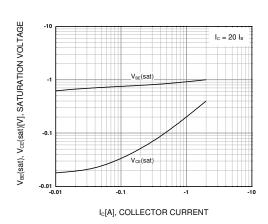


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

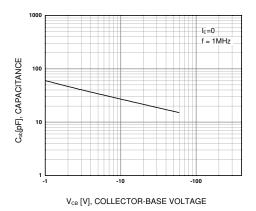


Figure 6. Collector Output Capacitance

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# Typical Characteristics (Continued)

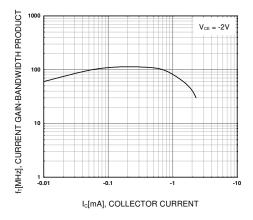


Figure 7. Current Gain Bandwidth Product

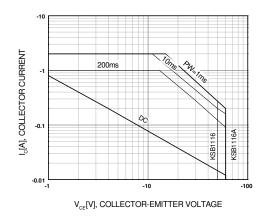


Figure 8. Safe Operating Area

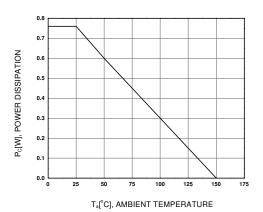
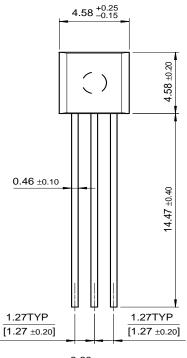


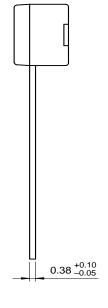
Figure 9. Power Derating

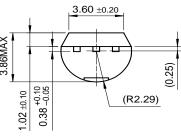
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KSB1116/1116A

**TO-92** 







Dimensions in Millimeters

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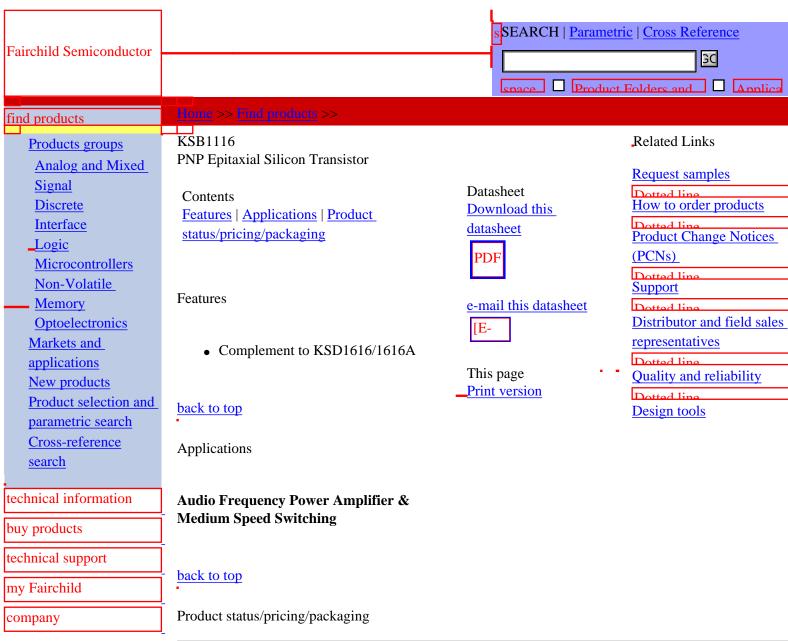
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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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Product	Product status	Pricing*	Package type	Leads	Packing method
KSB1116LBU	Full Production	\$0.075	<u>TO-92</u>	3	BULK
KSB1116SYTA	Full Production	\$0.075	<u>TO-92</u>	3	TAPE REEL
KSB1116GBU	Full Production	\$0.075	<u>TO-92</u>	3	BULK
KSB1116YBU	Full Production	\$0.075	<u>TO-92</u>	3	BULK
KSB1116SYBU	Full Production	\$0.075	<u>TO-92</u>	3	BULK
KSB1116LTA	Full Production	\$0.075	<u>TO-92</u>	3	TAPE REEL
KSB1116YTA	Full Production	\$0.075	<u>TO-92</u>	3	TAPE REEL
KSB1116GTA	Full Production	\$0.075	<u>TO-92</u>	3	TAPE REEL

<sup>\* 1,000</sup> piece Budgetary Pricing

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